

# 32K x 9 Bit Synchronous Dual I/O or Separate I/O Fast Static RAM with Parity Checker

The MCM62110 is a 294,912 bit synchronous static random access memory organized as 32,768 words of 9 bits, fabricated using Motorola's high-performance silicon-gate CMOS technology. The device integrates a 32K x 9 SRAM core with advanced peripheral circuitry consisting of address registers, two sets of input data registers, two sets of output latches, active high and active low chip enables, and a parity checker. The RAM checks odd parity during RAM read cycles. The data parity error (DPE) output is an open drain type output which indicates the result of this check. This device has increased output drive capability supported by multiple power pins. In addition, the output levels can be either 3.3 V or 5 V TTL compatible by choice of the appropriate output bus power supply.

The device has both asynchronous and synchronous inputs. Asynchronous inputs include the processor output enable ( $\overline{POE}$ ), system output enable ( $\overline{SOE}$ ), and the clock (K).

The address (A0 – A14) and chip enable ( $\overline{E1}$  and E2) inputs are synchronous and are registered on the falling edge of K. Write enable ( $\overline{W}$ ), processor input enable ( $\overline{PIE}$ ) and system input enable ( $\overline{SIE}$ ) are registered on the rising edge of K. Writes to the RAM are self-timed.

All data inputs/outputs, PDQ0 – PDQ7, SDQ0 – SDQ7, PDQP, and SDQP have input data registers triggered by the rising edge of the clock. These pins also have three-state output latches which are transparent during the high level of the clock and latched during the low level of the clock.

This device has a special feature which allows data to be passed through the RAM between the system and processor ports in either direction. This streaming is accomplished by latching in data from one port and asynchronously output enabling the other port. It is also possible to write to the RAM while streaming.

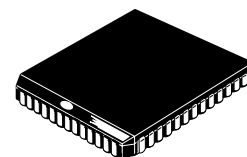
Additional power supply pins have been utilized for maximum performance. The output buffer power ( $V_{CCQ}$ ) and ground pins ( $V_{SSQ}$ ) are electrically isolated from  $V_{SS}$  and  $V_{CC}$ , and supply power and ground only to the output buffers. This allows connecting the output buffers to 3.3 V instead of 5.0 V if desired. If 3.3 V output levels are chosen, the output buffer impedance in the "high" state is approximately equal to the impedance in the "low" state thereby allowing simplified transmission line terminations.

The MCM62110 is available in a 52-pin plastic leaded chip carrier (PLCC).

This device is ideally suited for pipelined systems and systems with multiple data buses and multiprocessing systems, where a local processor has a bus isolated from a common system bus.

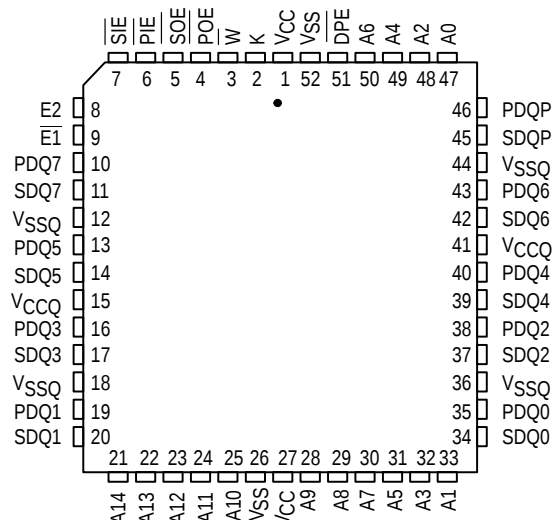
- Single 5 V  $\pm$  10% Power Supply
- Choice of 5 V or 3.3 V  $\pm$  10% Power Supplies for Output Level Compatibility
- Fast Access and Cycle Times: 15/17/20 ns Max
- Self-Timed Write Cycles
- Clock Controlled Output Latches
- Address, Chip Enable, and Data Input Registers
- Common Data Inputs and Data Outputs
- Dual I/O for Separate Processor and Memory Buses
- Separate Output Enable Controlled Three-State Outputs
- Odd Parity Checker During Reads
- Open Drain Output on Data Parity Error ( $\overline{DPE}$ ) Allowing Wire-ORing of Outputs
- High Output Drive Capability: 85 pF/Output at Rated Access Time
- High Board Density 52 Lead PLCC Package
- Active High and Low Chip Enables for Easy Memory Depth Expansion
- Can be used as Separate I/O x9

**MCM62110**



**FN PACKAGE  
PLASTIC  
CASE 778-02**

## PIN ASSIGNMENT

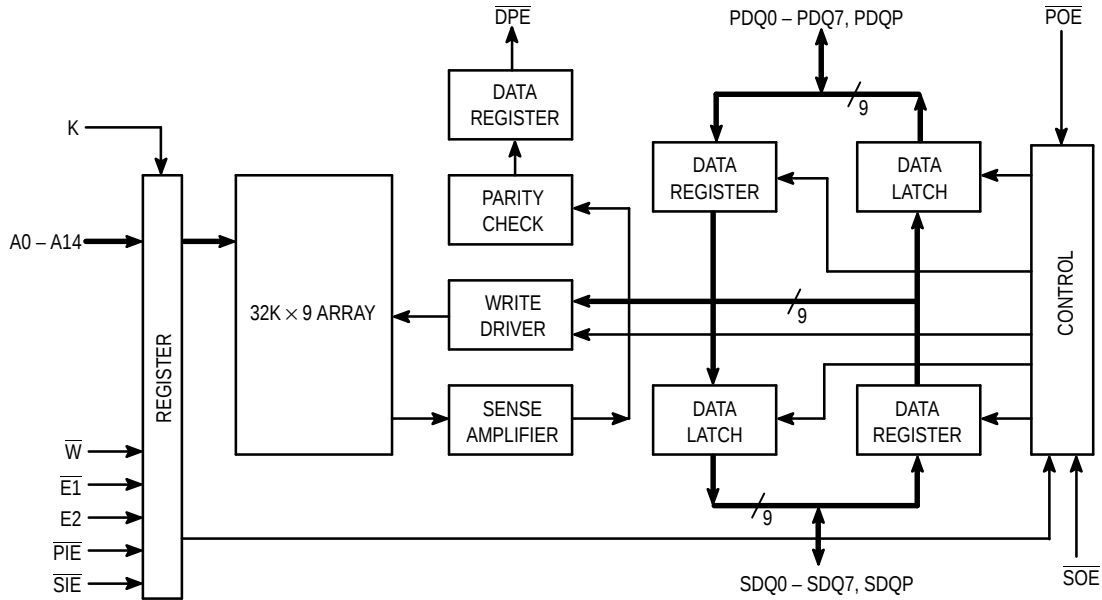


## PIN NAMES

|                  |                            |
|------------------|----------------------------|
| A0 – A14         | Address Inputs             |
| K                | Clock Input                |
| $\overline{W}$   | Write Enable               |
| $\overline{E1}$  | Active Low Chip Enable     |
| E2               | Active High Chip Enable    |
| $\overline{PIE}$ | Processor Input Enable     |
| $\overline{SIE}$ | System Input Enable        |
| $\overline{POE}$ | Processor Output Enable    |
| $\overline{SOE}$ | System Output Enable       |
| DPE              | Data Parity Error          |
| PDQ0 – PDQ7      | Processor Data I/O         |
| PDQP             | Processor Data Parity      |
| SDQ0 – SDQ7      | System Data I/O            |
| SDQP             | System Data Parity         |
| VCC              | + 5 V Power Supply         |
| VCCQ             | Output Buffer Power Supply |
| VSSQ             | Output Buffer Ground       |
| VSS              | Ground                     |

All power supply and ground pins must be connected for proper operation of the device.  
 $V_{CC} \geq V_{CCQ}$  at all times including power up.

### BLOCK DIAGRAM



**FUNCTIONAL TRUTH TABLE** (See Notes 1 and 2)

| <u>W</u> | <u>PIE</u> | <u>SIE</u> | <u>POE</u> | <u>SOE</u> | Mode  | Memory Subsystem Cycle | PDQ0 – PDQ7, PDQP Output | SDQ0 – SDQ7, SDQP Output | <u>DPE</u> | Notes |
|----------|------------|------------|------------|------------|-------|------------------------|--------------------------|--------------------------|------------|-------|
| 1        | 1          | 1          | 0          | 1          | Read  | Processor Read         | Data Out                 | High–Z                   | Parity Out | 3, 4  |
| 1        | 1          | 1          | 1          | 0          | Read  | Copy Back              | High–Z                   | Data Out                 | Parity Out | 3, 4  |
| 1        | 1          | 1          | 0          | 0          | Read  | Dual Bus Read          | Data Out                 | Data Out                 | Parity Out | 3, 4  |
| 1        | X          | X          | 1          | 1          | Read  | NOP                    | High–Z                   | High–Z                   | 1          |       |
| X        | 0          | 0          | X          | X          | N/A   | NOP                    | High–Z                   | High–Z                   | 1          | 2, 5  |
| 0        | 0          | 1          | 1          | 1          | Write | Processor Write Hit    | Data In                  | High–Z                   | 1          | 2, 6  |
| 0        | 1          | 0          | 1          | 1          | Write | Allocate               | High–Z                   | Data In                  | 1          | 2     |
| 0        | 0          | 1          | 1          | 0          | Write | Write Through          | Data In                  | Stream Data              | 1          | 2, 7  |
| 0        | 1          | 0          | 0          | 1          | Write | Allocate With Stream   | Stream Data              | Data In                  | 1          | 2, 7  |
| 1        | 0          | 1          | 1          | 0          | N/A   | Cache Inhibit Write    | Data In                  | Stream Data              | 1          | 2, 7  |
| 1        | 1          | 0          | 0          | 1          | N/A   | Cache Inhibit Read     | Stream Data              | Data In                  | 1          | 2, 7  |
| 0        | 1          | 1          | X          | X          | N/A   | NOP                    | High–Z                   | High–Z                   | 1          | 5     |
| X        | 0          | 1          | 0          | 0          | N/A   | Invalid                | Data In                  | Stream                   | 1          | 2, 8  |
| X        | 0          | 1          | 0          | 1          | N/A   | Invalid                | Data In                  | High–Z                   | 1          | 2, 8  |
| X        | 1          | 0          | 0          | 0          | N/A   | Invalid                | Stream                   | Data In                  | 1          | 2, 8  |
| X        | 1          | 0          | 1          | 0          | N/A   | Invalid                | High–Z                   | Data In                  | 1          | 2, 8  |

NOTES:

1. A '0' represents an input voltage  $\leq V_{IL}$  and a '1' represents an input voltage  $\geq V_{IH}$ . All inputs must satisfy the specified setup and hold times for the falling or rising edge of K. Some entries in this truth table represent latched values. This table assumes that the chip is selected (i.e.,  $\overline{E1} = 0$  and  $E2 = 1$ ) and  $V_{CC}$  current is equal to  $I_{CCA}$ . If this is not true, the chip will be in standby mode, the  $V_{CC}$  current will equal  $I_{SB1}$  or  $I_{SB2}$ .  $\overline{DPE}$  will default to 1 and all RAM outputs will be in High-Z. Other possible combinations of control inputs not covered by this note or the table above are not supported and the RAM's behavior is not specified.
2. If either  $\overline{IE}$  signal is sampled low on the rising edge of clock, the corresponding  $\overline{OE}$  is a don't care, and the corresponding outputs are High-Z.
3. A read cycle is defined as a cycle where data is driven on the internal data bus by the RAM.
4.  $\overline{DPE}$  is registered on the rising edge of K at the beginning of the following clock cycle
5. No RAM cycle is performed.
6. A write cycle is defined as a cycle where data is driven onto the internal data bus through one of the data I/O ports (PDQ0 – PDQ7 and PDQP or SDQ0 – SDQ7 and SPDQ), and written into the RAM.
7. Data is driven on the internal data bus by one I/O port through its data input register and latched into the data output latch of the other I/O port.
8. Data contention will occur.

## PARITY CHECKER

| Parity Scheme                                         | DPE |
|-------------------------------------------------------|-----|
| $\overline{E1} = V_{IH}$ and/or $E2 = V_{IL}$         | 1   |
| $RAMP = RAM0 \oplus RAM1 \oplus \dots \oplus RAM7$    | 1   |
| $RAMP \neq RAM0 \oplus RAM1 \oplus \dots \oplus RAM7$ | 0   |

NOTE: RAMP, RAM0, RAM1 . . . , refer to the data that is present on the RAMs internal bus, not necessarily data that resides in the RAM array. DPE is always delayed one clock, and is registered on the rising edge of K at the beginning of the following clock cycle (see AC CHARACTERISTICS).

## ABSOLUTE MAXIMUM RATINGS (Voltages Referenced to $V_{SS} = V_{SSQ} = 0$ V)

| Rating                                                                         | Symbol            | Value                   | Unit |
|--------------------------------------------------------------------------------|-------------------|-------------------------|------|
| Power Supply                                                                   | $V_{CC}$          | – 0.5 to + 7.0          | V    |
| Voltage Relative to $V_{SS}/V_{SSQ}$ for Any Pin Except $V_{CC}$ and $V_{CCQ}$ | $V_{in}, V_{out}$ | – 0.5 to $V_{CC} + 0.5$ | V    |
| Output Current (per I/O)                                                       | $I_{out}$         | ± 20                    | mA   |
| Power Dissipation                                                              | $P_D$             | 1.2                     | W    |
| Temperature Under Bias                                                         | $T_{bias}$        | – 10 to + 85            | °C   |
| Operating Temperature                                                          | $T_A$             | 0 to +70                | °C   |
| Storage Temperature                                                            | $T_{stg}$         | – 55 to + 125           | °C   |

NOTE: Permanent device damage may occur if ABSOLUTE MAXIMUM RATINGS are exceeded. Functional operation should be restricted to RECOMMENDED OPERATING CONDITIONS. Exposure to higher than recommended voltages for extended periods of time could affect device reliability.

This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high-impedance circuit.

This CMOS memory circuit has been designed to meet the dc and ac specifications shown in the tables, after thermal equilibrium has been established.

This device contains circuitry that will ensure the output devices are in High-Z at power up.

## DC OPERATING CONDITIONS AND CHARACTERISTICS

( $V_{CC} = 5.0 \text{ V} \pm 10\%$ ,  $V_{CCQ} = 5.0 \text{ V}$  or  $3.3 \text{ V} \pm 10\%$ ,  $T_A = 0$  to  $+70^\circ\text{C}$ , Unless Otherwise Noted)

### RECOMMENDED OPERATING CONDITIONS (Voltages referenced to $V_{SS} = V_{SSQ} = 0 \text{ V}$ )

| Parameter                                                                             | Symbol    | Min        | Max            | Unit |
|---------------------------------------------------------------------------------------|-----------|------------|----------------|------|
| Supply Voltage (Operating Voltage Range)                                              | $V_{CC}$  | 4.5        | 5.5            | V    |
| Output Buffer Supply Voltage (5.0 V TTL Compatible)<br>(3.3 V 50 $\Omega$ Compatible) | $V_{CCQ}$ | 4.5<br>3.0 | 5.5<br>3.6     | V    |
| Input High Voltage                                                                    | $V_{IH}$  | 2.2        | $V_{CC} + 0.3$ | V    |
| Input Low Voltage                                                                     | $V_{IL}$  | -0.5*      | 0.8            | V    |

\*  $V_{IL}(\text{min}) = -3.0 \text{ V}$  ac (pulse width  $\leq 20 \text{ ns}$ )

### DC CHARACTERISTICS

| Parameter                                                                                                                                                                                   | Symbol       | Min         | Max               | Unit                                                                                                                          |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------|-------------|-------------------|-------------------------------------------------------------------------------------------------------------------------------|
| Input Leakage Current (All Inputs, $V_{in} = 0$ to $V_{CC}$ )                                                                                                                               | $I_{lkg(I)}$ | —           | $\pm 1.0$         | $\mu\text{A}$                                                                                                                 |
| Output Leakage Current ( $\overline{POE}$ , $\overline{SOE} = V_{IH}$ )                                                                                                                     | $I_{lkg(O)}$ | —           | $\pm 1.0$         | $\mu\text{A}$                                                                                                                 |
| AC Supply Current (All Inputs = $V_{IL}$ or $V_{IH}$ , $V_{IL} = 0.0 \text{ V}$ and $V_{IH} \geq 3.0 \text{ V}$ ,<br>$I_{out} = 0 \text{ mA}$ , Cycle Time $\geq t_{KHKH}$ min)             | $I_{CCA}$    | —<br>—<br>— | 190<br>190<br>190 | mA                                                                                                                            |
|                                                                                                                                                                                             |              |             |                   | MCM62110-15: $t_{KHKH} = 15 \text{ ns}$<br>MCM62110-17: $t_{KHKH} = 17 \text{ ns}$<br>MCM62110-20: $t_{KHKH} = 20 \text{ ns}$ |
| TTL Standby Current ( $V_{CC} = \text{Max}$ , $\overline{E1} = V_{IH}$ or $E2 = V_{IL}$ )                                                                                                   | $I_{SB1}$    | —           | 40                | mA                                                                                                                            |
| CMOS Standby Current ( $V_{CC} = \text{Max}$ , $f = 0 \text{ MHz}$ , $\overline{E1} = V_{IH}$ or $E2 = V_{IL}$ ,<br>$V_{in} \leq V_{SS} + 0.2 \text{ V}$ or $\geq V_{CC} - 0.2 \text{ V}$ ) | $I_{SB2}$    | —           | 30                | mA                                                                                                                            |
| Output Low Voltage ( $I_{OL} = +8.0 \text{ mA}$ , $\overline{DPE}$ : $I_{OL} = +23.0 \text{ mA}$ )                                                                                          | $V_{OL}$     | —           | 0.4               | V                                                                                                                             |
| Output High Voltage ( $I_{OH} = -4.0 \text{ mA}$ )                                                                                                                                          | $V_{OH}$     | 2.4         | —                 | V                                                                                                                             |

### CAPACITANCE ( $f = 1.0 \text{ MHz}$ , $dV = 3.0 \text{ V}$ , $T_A = 25^\circ\text{C}$ , Periodically Sampled Rather Than 100% Tested)

| Parameter                                                       | Symbol         | Typ | Max | Unit |
|-----------------------------------------------------------------|----------------|-----|-----|------|
| Input Capacitance (All Pins Except I/Os)                        | $C_{in}$       | 2   | 3   | pF   |
| Input/Output Capacitance (PDQ0 – PDQ7, SDQ0 – SDQ7, PDQP, SDQP) | $C_{out}$      | 6   | 7   | pF   |
| Data Parity Error Output Capacitance ( $\overline{DPE}$ )       | $C_{out(DPE)}$ | 6   | 7   | pF   |

### AC SPEC LOADS

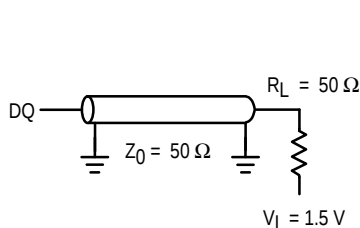


Figure 1A

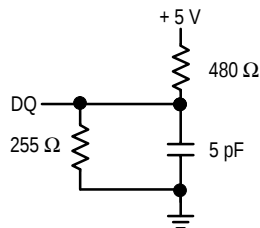


Figure 1B

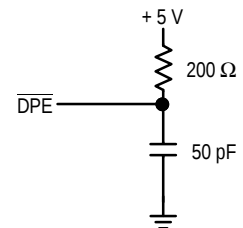


Figure 1C

## AC OPERATING CONDITIONS AND CHARACTERISTICS

(V<sub>CC</sub> = 5.0 V ± 10%, V<sub>CCQ</sub> = 5.0 V or 3.3 V ± 10%, T<sub>A</sub> = 0 to + 70°C, Unless Otherwise Noted)

Input Timing Measurement Reference Level ..... 1.5 V  
 Input Pulse Levels ..... 0 to 3.0 V  
 Input Rise/Fall Time ..... 3 ns

Output Measurement Timing Level ..... 1.5 V  
 Output Load ..... See Figure 1A Unless Otherwise Noted

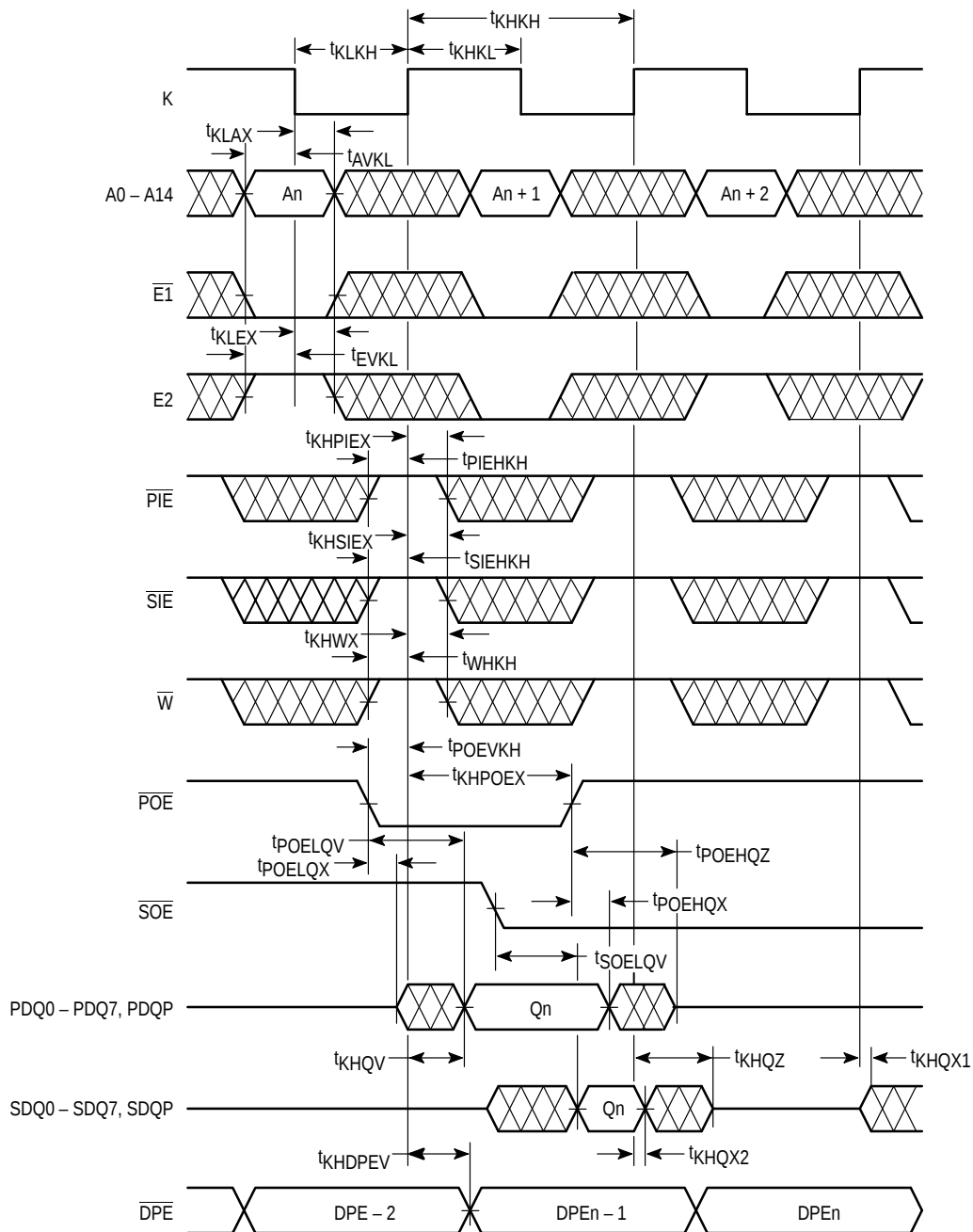
### READ CYCLE (See Note 1)

| Parameter                                                                                                                                                                                                                                                                                                                               | Symbol                                     | MCM62110–15 |     | MCM62110–17 |     | MCM62110–20 |     | Unit               | Notes |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------|-------------|-----|-------------|-----|-------------|-----|--------------------|-------|
|                                                                                                                                                                                                                                                                                                                                         |                                            | Min         | Max | Min         | Max | Min         | Max |                    |       |
| Read Cycle Time Clock High to Clock High                                                                                                                                                                                                                                                                                                | t <sub>KHKH</sub>                          | 15          | —   | 17          | —   | 20          | —   | ns                 | 1, 2  |
| Clock Low Pulse Width                                                                                                                                                                                                                                                                                                                   | t <sub>KLKH</sub>                          | 5           | —   | 5           | —   | 5           | —   | ns                 |       |
| Clock High Pulse Width                                                                                                                                                                                                                                                                                                                  | t <sub>KHKL</sub>                          | 7           | —   | 7           | —   | 7           | —   | ns                 |       |
| Clock High to $\overline{\text{DPE}}$ Valid                                                                                                                                                                                                                                                                                             | t <sub>KHDPEV</sub>                        | —           | 7   | —           | 8   | —           | 10  | ns                 | 5     |
| Clock High to Output Valid                                                                                                                                                                                                                                                                                                              | t <sub>KHQV</sub>                          | —           | 7   | —           | 7.5 | —           | 10  | ns                 | 4, 3  |
| Clock (K) High to Output Low Z After Write                                                                                                                                                                                                                                                                                              | t <sub>KHQX1</sub>                         | 8           | —   | 8           | —   | 8           | —   | ns                 |       |
| Output Hold from Clock High                                                                                                                                                                                                                                                                                                             | t <sub>KHQX2</sub>                         | 5           | —   | 5           | —   | 5           | —   | ns                 | 4, 6  |
| Clock High to Q High–Z ( $\overline{\text{E1}}$ or E2 = False)                                                                                                                                                                                                                                                                          | t <sub>KHQZ</sub>                          | —           | 8   | —           | 9   | —           | 10  | ns                 | 6     |
| Setup Times:<br><div><div><div>A</div><div>W</div><div><math>\overline{\text{E1}}</math>, E2</div><div>PIE</div><div>SIE</div><div>POE</div><div>SOE</div></div><div>t<sub>AVKL</sub><br/>t<sub>WHKH</sub><br/>t<sub>EVKL</sub><br/>t<sub>PIEHKH</sub><br/>t<sub>SIEHKH</sub><br/>t<sub>POEVKH</sub><br/>t<sub>SOEVKH</sub></div></div> | 2.5                                        | —           | 2.5 | —           | 2.5 | —           | ns  | <div>7<br/>7</div> |       |
| Hold Times:<br><div><div><div>A</div><div>W</div><div><math>\overline{\text{E1}}</math>, E2</div><div>PIE</div><div>SIE</div><div>POE</div><div>SOE</div></div><div>t<sub>KLAX</sub><br/>t<sub>KHWX</sub><br/>t<sub>KLEX</sub><br/>t<sub>KHPIEX</sub><br/>t<sub>KHSIEX</sub><br/>t<sub>KHPOEX</sub><br/>t<sub>KHSOEX</sub></div></div>  | 2                                          | —           | 2   | —           | 2   | —           | ns  | <div>7<br/>7</div> |       |
| Output Enable High to Q High–Z                                                                                                                                                                                                                                                                                                          | t <sub>POEHQZ</sub><br>t <sub>SOEHQZ</sub> | 0           | 8   | 0           | 9   | 0           | 9   | ns                 | 6     |
| Output Hold from Output Enable High                                                                                                                                                                                                                                                                                                     | t <sub>POEHQX</sub><br>t <sub>SOEHQX</sub> | 5           | —   | 5           | —   | 5           | —   | ns                 | 6     |
| Output Enable Low to Q Active                                                                                                                                                                                                                                                                                                           | t <sub>POELQX</sub><br>t <sub>SOELQX</sub> | 0           | —   | 0           | —   | 0           | —   | ns                 | 6     |
| Output Enable Low to Output Valid                                                                                                                                                                                                                                                                                                       | t <sub>POELQV</sub><br>t <sub>SOELQV</sub> | —           | 5   | —           | 6   | —           | 8   | ns                 |       |

#### NOTES:

1. A read is defined by  $\overline{W}$  high for the setup and hold times.
2. All read cycle timing is referenced from K, SOE, or POE.
3. Access time is controlled by t<sub>KLQV</sub> if the clock low pulse width is less than (t<sub>KLQV</sub> - t<sub>KHQV</sub>); otherwise it is controlled by KHQV.
4. K must be at a high level for outputs to transition.
5. DPE is valid exactly one clock cycle after the output data is valid.
6. Transition is measured ± 500 mV from steady-state voltage with output load of Figure 1B. This parameter is sampled and not 100% tested.  
At any given voltage and temperature, t<sub>KHQZ</sub> is less than t<sub>KHQX</sub>, t<sub>POEHQZ</sub> is less than t<sub>POELQX</sub> for a given device, and t<sub>SOEHQZ</sub> is less than t<sub>SOELQX</sub> for a given device.
7. These read cycle timings are used to guarantee proper parity operation only.

# READ CYCLE (See Notes)



## NOTES:

1. DPE is valid exactly one clock cycle after the output data is valid.

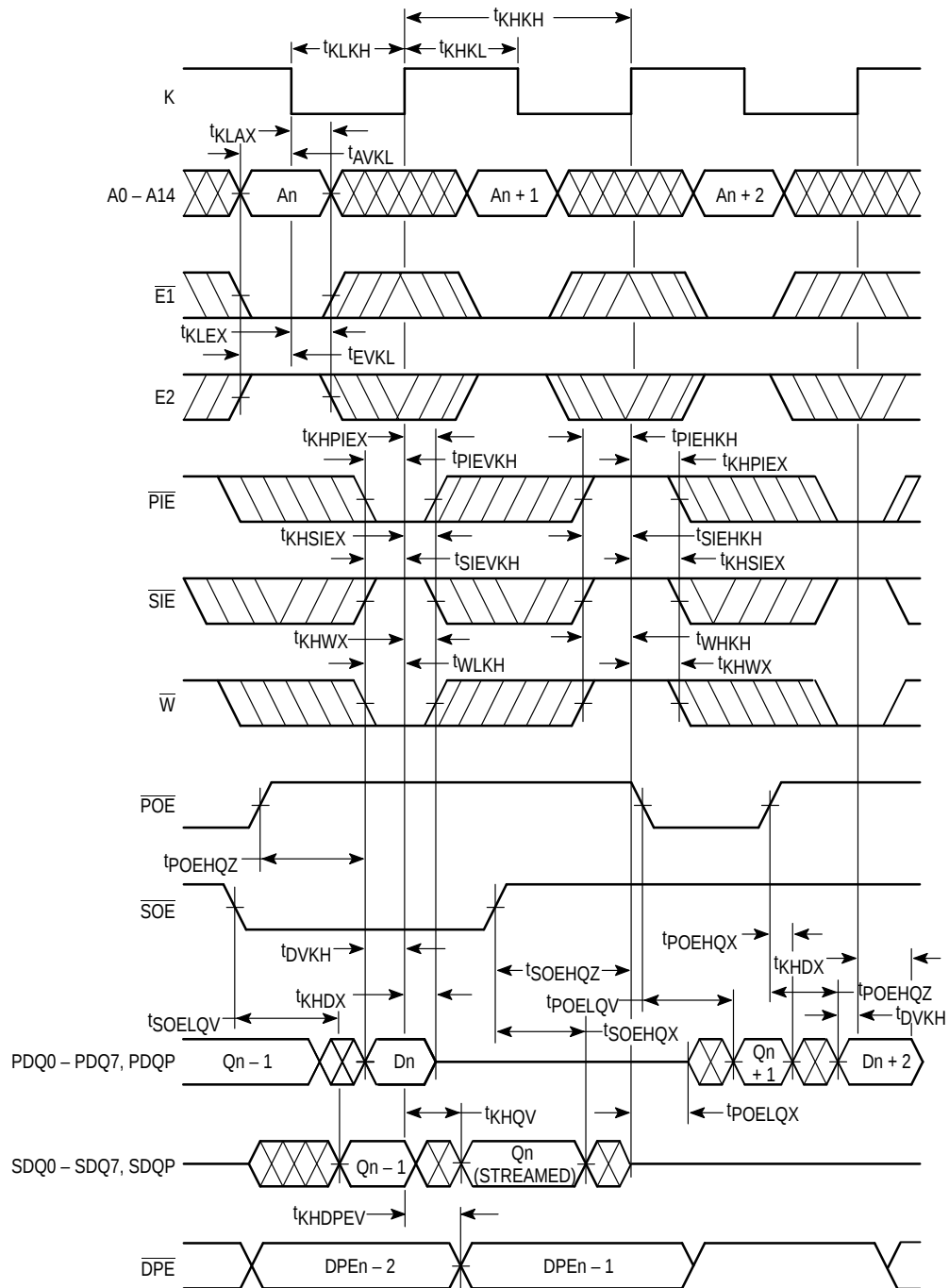
**WRITE CYCLE** (See Note 1)

| Parameter                                                                                                                                       | Symbol                                                                                | MCM62110-15 |     | MCM62110-17 |     | MCM62110-20 |     | Unit | Notes |
|-------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------|-------------|-----|-------------|-----|-------------|-----|------|-------|
|                                                                                                                                                 |                                                                                       | Min         | Max | Min         | Max | Min         | Max |      |       |
| Write Cycle Times                                                                                                                               | $t_{KHKH}$                                                                            | 15          | —   | 17          | —   | 20          | —   | ns   | 1, 2  |
| Clock Low Pulse Width                                                                                                                           | $t_{KLKH}$                                                                            | 5           | —   | 5           | —   | 5           | —   | ns   |       |
| Clock High Pulse Width                                                                                                                          | $t_{KHKL}$                                                                            | 7           | —   | 7           | —   | 7           | —   | ns   |       |
| Clock High to Output High-Z ( $\overline{W} = V_{IL}$ and $\overline{SIE} = \overline{PIE} = V_{IH}$ )                                          | $t_{KHQZ}$                                                                            | —           | 8   | —           | 9   | —           | 10  | ns   | 3, 4  |
| Setup Times:<br>A<br>$\overline{W}$<br>$\overline{E1}, E2$<br>$\overline{PIE}$<br>$\overline{SIE}$<br>SDQ0 – SDQ7, SDQP, PDQ0 – PDQ7, PDQP      | $t_{AVKL}$<br>$t_{WLKH}$<br>$t_{EVKL}$<br>$t_{PIEVKH}$<br>$t_{SIEVKH}$<br>$t_{DVKH}$  | 2.5         | —   | 2.5         | —   | 2.5         | —   | ns   |       |
| Hold Times:<br>A<br>$\overline{W}$<br>$\overline{E1}, E2$<br>$\overline{PIE}$<br>$\overline{SIE}$<br>SDQ0 – SDQ7, SDQP, PDQ0 – PDQ7, PDQP       | $t_{KLAX}$<br>$t_{KH WX}$<br>$t_{KLEX}$<br>$t_{KHPIEX}$<br>$t_{KHSIEX}$<br>$t_{KHDX}$ | 2           | —   | 2           | —   | 2           | —   | ns   |       |
| Write with Streaming ( $\overline{PIE} = \overline{SOE} = V_{IL}$ or $\overline{SIE} = \overline{POE} = V_{IL}$ )<br>Clock High to Output Valid | $t_{KHQV}$                                                                            | —           | 7   | —           | 7.5 | —           | 8   | ns   | 5     |
| Output Enable High to Q High-Z                                                                                                                  | $t_{POEHQZ}$<br>$t_{SOEHQZ}$                                                          | 0           | 8   | 0           | 9   | 0           | 9   | ns   | 6     |
| Output Hold from Output Enable High                                                                                                             | $t_{POEHQX}$<br>$t_{SOEHQX}$                                                          | 5           | —   | 5           | —   | 5           | —   | ns   |       |
| Output Enable Low to Q Active                                                                                                                   | $t_{POELQX}$<br>$t_{SOELQX}$                                                          | 0           | —   | 0           | —   | 0           | —   | ns   | 6     |
| Output Enable Low to Output Valid                                                                                                               | $t_{POELQV}$<br>$t_{SOELQV}$                                                          | —           | 5   | —           | 6   | —           | 8   | ns   |       |

**NOTES:**

1. A write is performed with  $\overline{W} = V_{IL}$ ,  $\overline{E1} = V_{IL}$ ,  $E2 = V_{IH}$  for the specified setup and hold times and either  $\overline{PIE} = V_{IL}$  or  $\overline{SIE} = V_{IL}$ . If both  $\overline{PIE} = V_{IL}$  and  $\overline{SIE} = V_{IL}$  or  $\overline{PIE} = V_{IH}$  and  $\overline{SIE} = V_{IH}$ , then this is treated like a NOP and no write is performed.
2. All write cycle timings are referenced from K.
3. K must be at a high level for the outputs to transition.
4. Transition is measured  $\pm 500$  mV from steady-state voltage with output load of Figure 1B. This parameter is sampled and not 100% tested. At any given voltage and temperature,  $t_{KHQZ}$  is less than  $t_{KHQX}$  for a given device.
5. A write with streaming is defined as a write cycle which writes data from one data bus to the array and outputs the same data onto the other data bus.
6. Transition is measured  $\pm 500$  mV from steady-state voltage with output load of Figure 1B. This parameter is sampled and not 100% tested. At any given voltage and temperature,  $t_{KHQZ}$  is less than  $t_{KHQX}$ ,  $t_{POEHQZ}$  is less than  $t_{POELQX}$  for a given device, and  $t_{SOEHQZ}$  is less than  $t_{SOELQX}$  for a given device.

# WRITE THROUGH — READ — WRITE (See Note)



NOTE:  $\overline{DPE}$  is valid exactly one clock cycle after the output data is written.

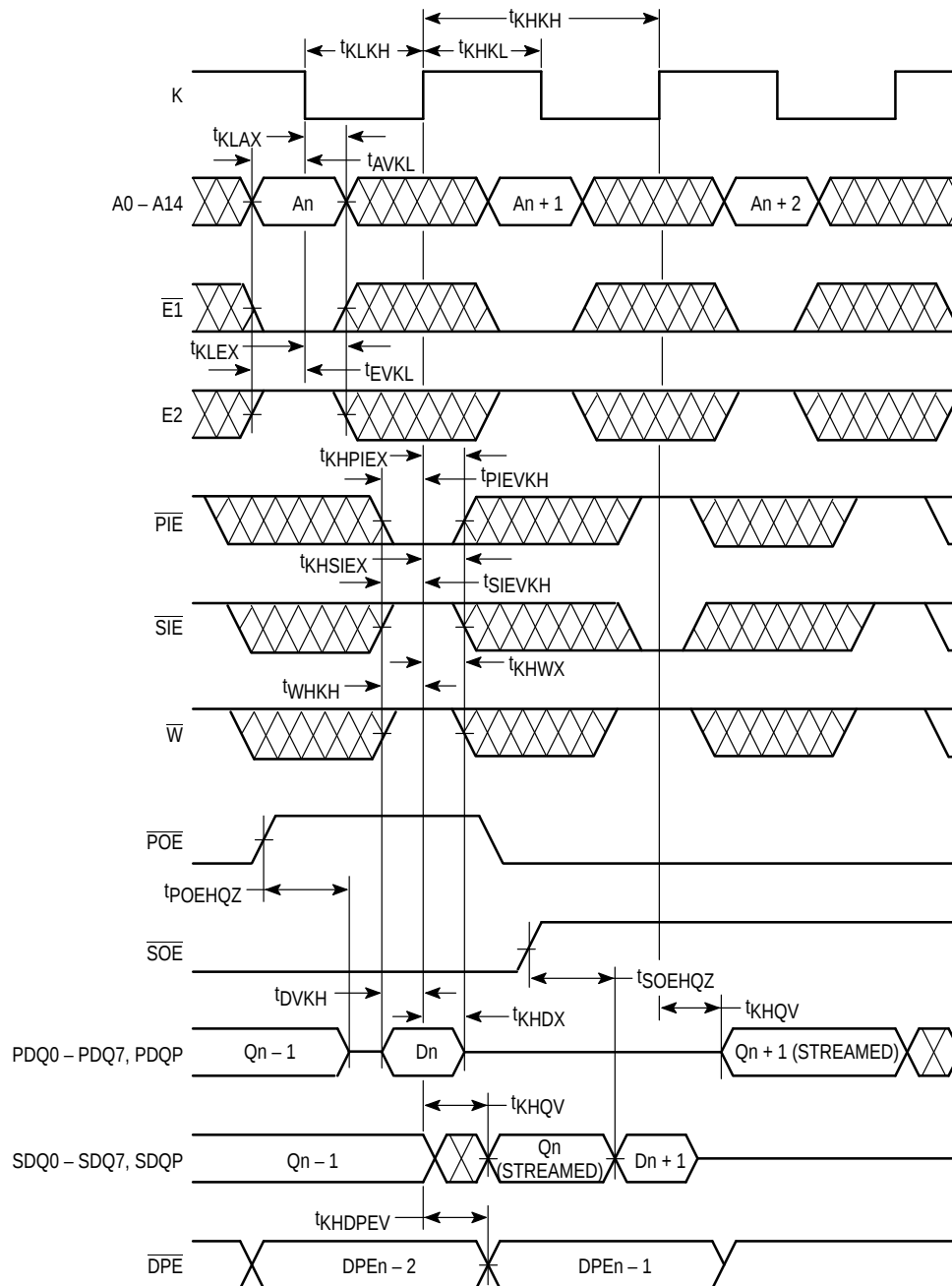
**STREAM CYCLE** (See Note 1)

| Parameter                                                                              | Symbol                                                                                                                         | MCM62110-15 |     | MCM62110-17 |     | MCM62110-20 |     | Unit | Notes |
|----------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------|-------------|-----|-------------|-----|-------------|-----|------|-------|
|                                                                                        |                                                                                                                                | Min         | Max | Min         | Max | Min         | Max |      |       |
| Stream Cycle Time                                                                      | t <sub>KHKH</sub>                                                                                                              | 15          | —   | 17          | —   | 20          | —   | ns   | 1, 2  |
| Clock Low Pulse Width                                                                  | t <sub>KLKH</sub>                                                                                                              | 5           | —   | 5           | —   | 5           | —   | ns   |       |
| Clock High Pulse Width                                                                 | t <sub>KHKL</sub>                                                                                                              | 7           | —   | 7           | —   | 7           | —   | ns   |       |
| Stream Access Time                                                                     | t <sub>KHQV</sub>                                                                                                              | —           | 7   | —           | 7.5 | —           | 8   | ns   |       |
| Setup Times:<br>A<br>W<br>E1, E2<br>PIE<br>SIE<br>SDQ0 – SDQ7, SDQP, PDQ0 – PDQ7, PDQP | t <sub>AVKL</sub><br>t <sub>WHKH</sub><br>t <sub>EVKL</sub><br>t <sub>PIEVKH</sub><br>t <sub>SIEVKH</sub><br>t <sub>DVKH</sub> | 2.5         | —   | 2.5         | —   | 2.5         | —   | ns   |       |
| Hold Times:<br>A<br>W<br>E1, E2<br>PIE<br>SIE<br>SDQ0 – SDQ7, SDQP, PDQ0 – PDQ7, PDQP  | t <sub>KLAX</sub><br>t <sub>KHWH</sub><br>t <sub>KLEX</sub><br>t <sub>KHPIEX</sub><br>t <sub>KHSIEX</sub><br>t <sub>KHDX</sub> | 2           | —   | 2           | —   | 2           | —   | ns   |       |
| Output Enable High to Q High-Z                                                         | t <sub>POEHQZ</sub><br>t <sub>SOEHQZ</sub>                                                                                     | 0           | 8   | 0           | 9   | 0           | 9   | ns   | 3     |
| Output Enable Low to Q Active                                                          | t <sub>POELQX</sub><br>t <sub>SOELQX</sub>                                                                                     | 0           | —   | 0           | —   | 0           | —   | ns   | 3     |
| Output Enable Low to Output Valid                                                      | t <sub>POELQV</sub><br>t <sub>SOELQV</sub>                                                                                     | —           | 5   | —           | 6   | —           | 8   | ns   |       |

**NOTES:**

1. A stream cycle is defined as a cycle where data is passed from one data bus to the other data bus.
2. All stream cycle timing is referenced from K.
3. Transition is measured  $\pm 500$  mV from steady-state voltage with output load of Figure 1B. This parameter is sampled and not 100% tested. At any given voltage and temperature, t<sub>POEHQZ</sub> is less than t<sub>POELQX</sub>, t<sub>SOEHQZ</sub> is less than t<sub>SOELQX</sub>, and t<sub>KHQZ</sub> is less than t<sub>KHQX</sub> for a given device.

# **STREAM CYCLE (See Note)**



NOTE:  $\overline{DPE}$  is valid exactly one clock cycle after the output data is valid.

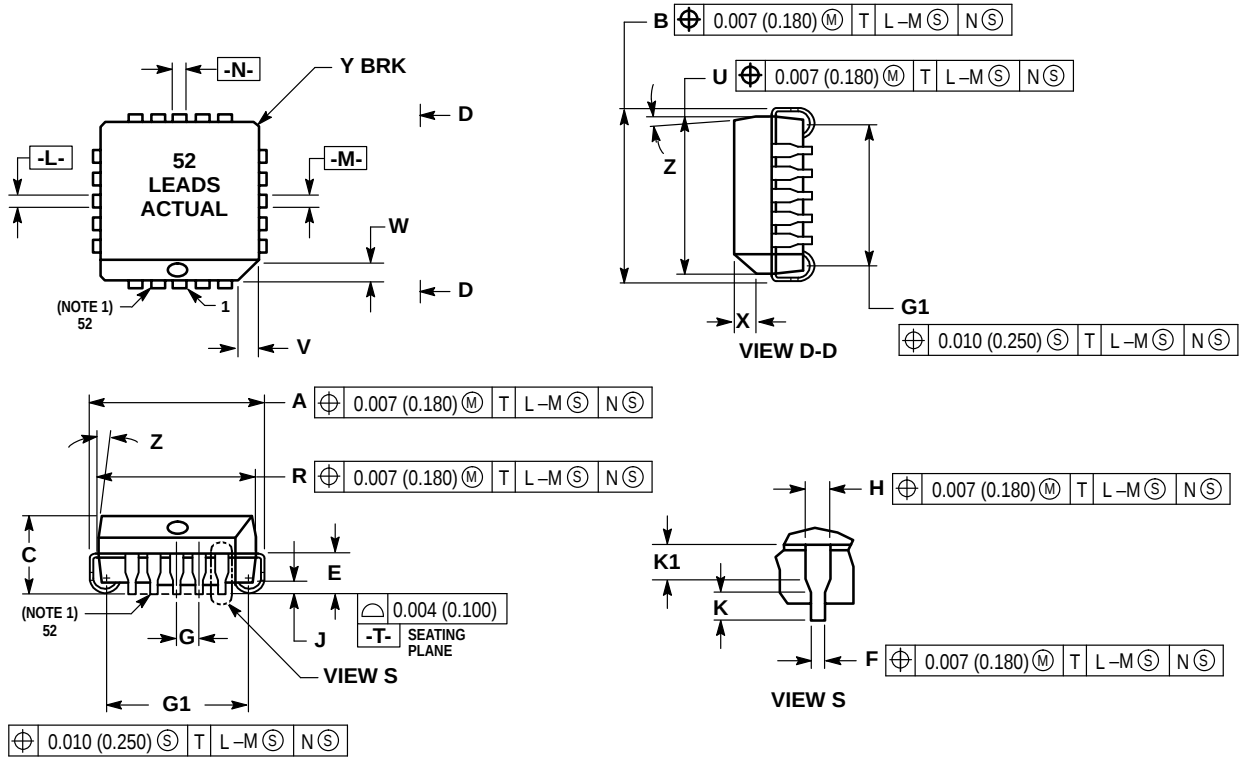
## **ORDERING INFORMATION** (Order by Full Part Number)

Motorola Memory Prefix **MCM** **62110** **FN** **XX** Speed (15 = 15 ns, 17 = 17 ns, 20 = 20 ns)  
Part Number \_\_\_\_\_ Package (FN = PLCC)

Full Part Numbers — MCM62110FN15 MCM62110FN17 MCM62110FN20

## PACKAGE DIMENSIONS

### FN PACKAGE 52-LEAD PLCC CASE 778-02



#### NOTES:

1. DUE TO SPACE LIMITATION, CASE 778-02 SHALL BE REPRESENTED BY A GENERAL (SMALLER) CASE OUTLINE DRAWING RATHER THAN SHOWING ALL 52 LEADS.
2. DATUMS -L-, -M-, AND -N- DETERMINED WHERE TOP OF LEAD SHOULDER EXITS PLASTIC BODY AT MOLD PARTING LINE.
3. DIM G1, TRUE POSITION TO BE MEASURED AT DATUM -T-, SEATING PLANE.
4. DIM R AND U DO NOT INCLUDE MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.
5. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
6. CONTROLLING DIMENSION: INCH.
7. THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
8. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

| DIM | INCHES    |       | MILLIMETERS |       |
|-----|-----------|-------|-------------|-------|
|     | MIN       | MAX   | MIN         | MAX   |
| A   | 0.785     | 0.795 | 19.94       | 20.19 |
| B   | 0.785     | 0.795 | 19.94       | 20.19 |
| C   | 0.165     | 0.180 | 4.20        | 4.57  |
| E   | 0.090     | 0.110 | 2.29        | 2.79  |
| F   | 0.013     | 0.019 | 0.33        | 0.48  |
| G   | 0.050 BSC |       | 1.27 BSC    |       |
| H   | 0.026     | 0.032 | 0.66        | 0.81  |
| J   | 0.020     | —     | 0.51        | —     |
| K   | 0.025     | —     | 0.64        | —     |
| R   | 0.750     | 0.756 | 19.05       | 19.20 |
| U   | 0.750     | 0.756 | 19.05       | 19.20 |
| V   | 0.042     | 0.048 | 1.07        | 1.21  |
| W   | 0.042     | 0.048 | 1.07        | 1.21  |
| X   | 0.042     | 0.056 | 1.07        | 1.42  |
| Y   | —         | 0.020 | —           | 0.50  |
| Z   | 2°        | 10°   | 2°          | 10°   |
| G1  | 0.710     | 0.730 | 18.04       | 18.54 |
| K1  | 0.040     | —     | 1.02        | —     |

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**MCM62110/D**





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